

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re patent application of

Noboru ICHINOSE, et al.

Serial No.: Not Yet Assigned Group Art Unit: Not Yet Assigned

Filing Date: Concurrently Herewith Examiner: Not Yet Assigned

For: SEMICONDUCTOR LAYER

Honorable Commissioner of Patents  
Alexandria, Virginia 22313-1450

## INFORMATION DISCLOSURE STATEMENT

Sir:

Under the provisions of 37 CFR §1.97 through §1.98 and pursuant to applicants' duty of disclosure under 37 CFR §1.56, applicants respectfully bring the following documents listed on the attached form PTO-1449 and cited in the International Search Report (PCT Form PCT/ISA/210) and International Preliminary Examination Report in a counterpart foreign application, to the attention of the Examiner in charge of the above-identified application. Copies of the listed documents are provided herewith for the convenience of the Examiner. Further, in compliance with the concise explanation requirement under 37 CFR §1.98(a)(3) for foreign language documents, English-language Abstracts are attached to the references.

This citation does not constitute an admission that the references are relevant or material to the claims. They are only cited as constituting related art of which applicants are aware.

It is respectfully requested that the listed references be considered by the Examiner and formally made of record in this application.

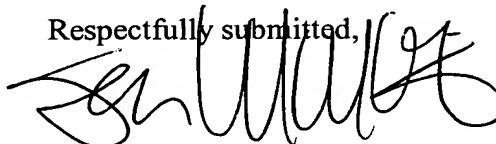
Please charge any deficiencies in fees and credit any overpayment of fees to Attorney's Deposit Account No. 50-0481.

Date:

2/7/06

MCGINN INTELLECTUAL PROPERTY  
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Respectfully submitted,



Sean M. McGinn, Esq.

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**INFORMATION DISCLOSURE CITATION**  
(Use several sheets if necessary)

Docket Number (Optional)

PKHF-04053US

Application Number

Not Yet Assigned

104567369

Applicant(s)

Noboru ICHINOSE, et al

JAP9 Rec'd PCT/PTO 07 FEB 2006

Filing Date

Concurrently Herewith

Group Art Unit

Not Yet Assigned

**U.S. PATENT DOCUMENTS**

*EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE

**U.S. PATENT APPLICATION PUBLICATIONS**

*EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE

**FOREIGN PATENT DOCUMENTS**

	REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
							YES	NO
		2003-46128	02/14/2003	JAPAN			ABS	
		2000-349336	12/15/2000	JAPAN			ABS	

**OTHER DOCUMENTS**

(Including Author, Title, Date, Pertinent Pages, Etc.)

Yang, Ying-Ge, "Preparation and Structural Properties for GaN Films Grown on Si (1 1 1) by Annealing",  
Applied Surface Science, Vol. 193, 2002, pages 254 -260

EXAMINER

DATE CONSIDERED

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.